

Upscaling perovskite solar cells

Jun-Ho Yum, Soo-Jin Moon, Laurent Sansonnens, Linus Löfgren, Sylvain Nicolay, Julien Bailat, Christophe Ballif

PV-Center, CSEM, Jaquet Droz 1, 2002 Neuchâtel



Motivation

Upscaling of perovskite solar cell for ultra-high performance tandem photovoltaic energy system

What is the top cell material on Si-bottom cell?

The **organometallic halide perovskite**

Record efficiency: **17.9%** (KRICT, certified by NREL)

http://www.nrel.gov/ncpv/images/efficiency_chart.jpg

What are the advantages of the organometallic halide perovskite?

1. Tunable dimensionality
2. Tunable optical and electronic property
3. Low-cost process-based solution process
4. High molar extinction efficient
5. Steep absorption onset and no optically detected deep states

However, all reported high performance have been achieved on laboratory scale area below **0.5 cm²**.

CSEM task is to upscale perovskite solar cell:

CSEM will focus on optimizing perovskite layer *via* production-oriented processes such as wet coating, spin-coating or new innovative coating, with the final aim of transferring the high efficiency achieved in the labs to pre-production scale mini-modules

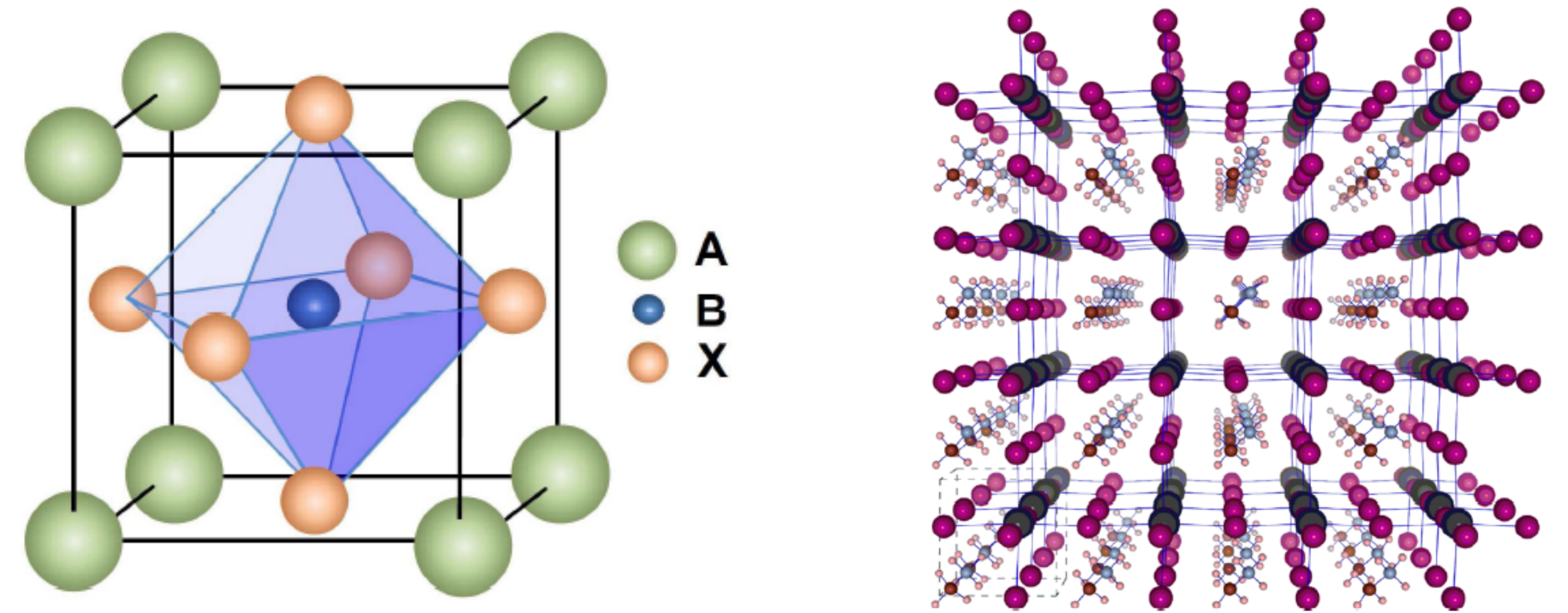


Figure 1. Perovskite structure (Hui Seon Kim et al., J. Phys. Chem. C 2014, 118, 5615)

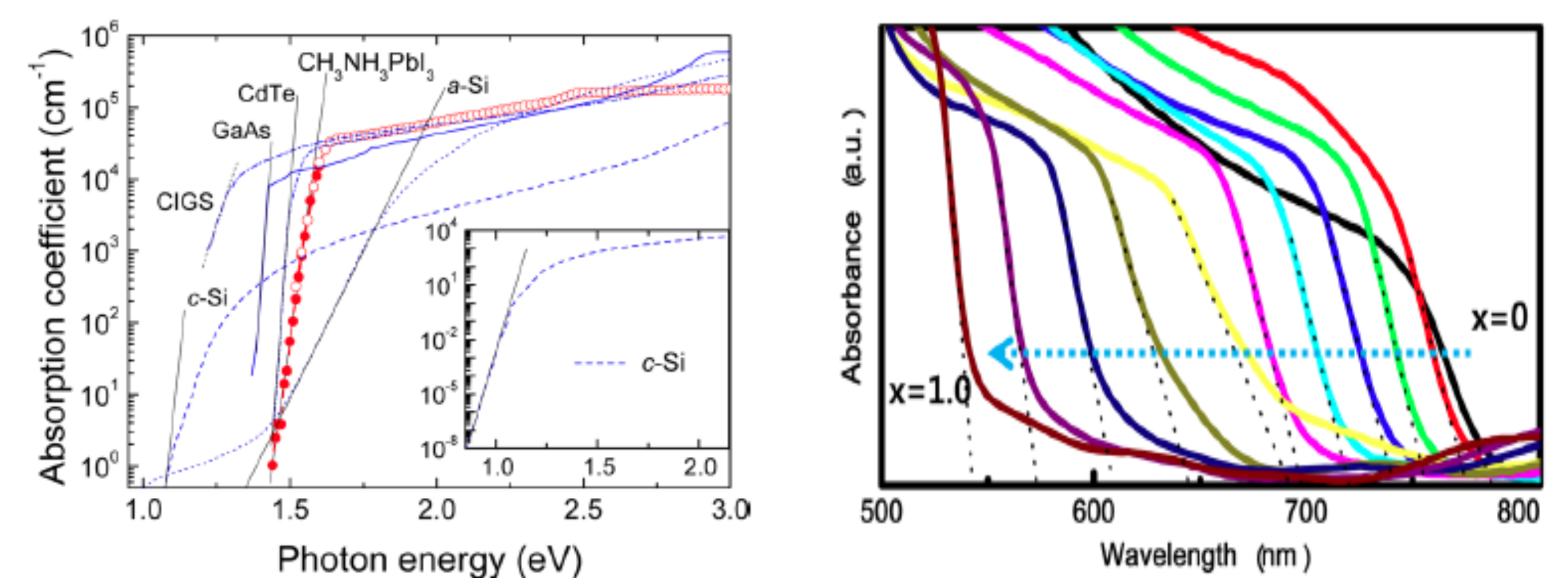


Figure 2. (Left) Absorption coefficient of CH₃NH₃PbI₃ perovskite compared to other photovoltaic materials (Stefaan De Wolf et al., J. Phys. Chem. C 2014, 5, 1035) and (Right) absorption spectra of CH₃NH₃Pb(I_{1-x}Br_x)₃.

Device fabrication

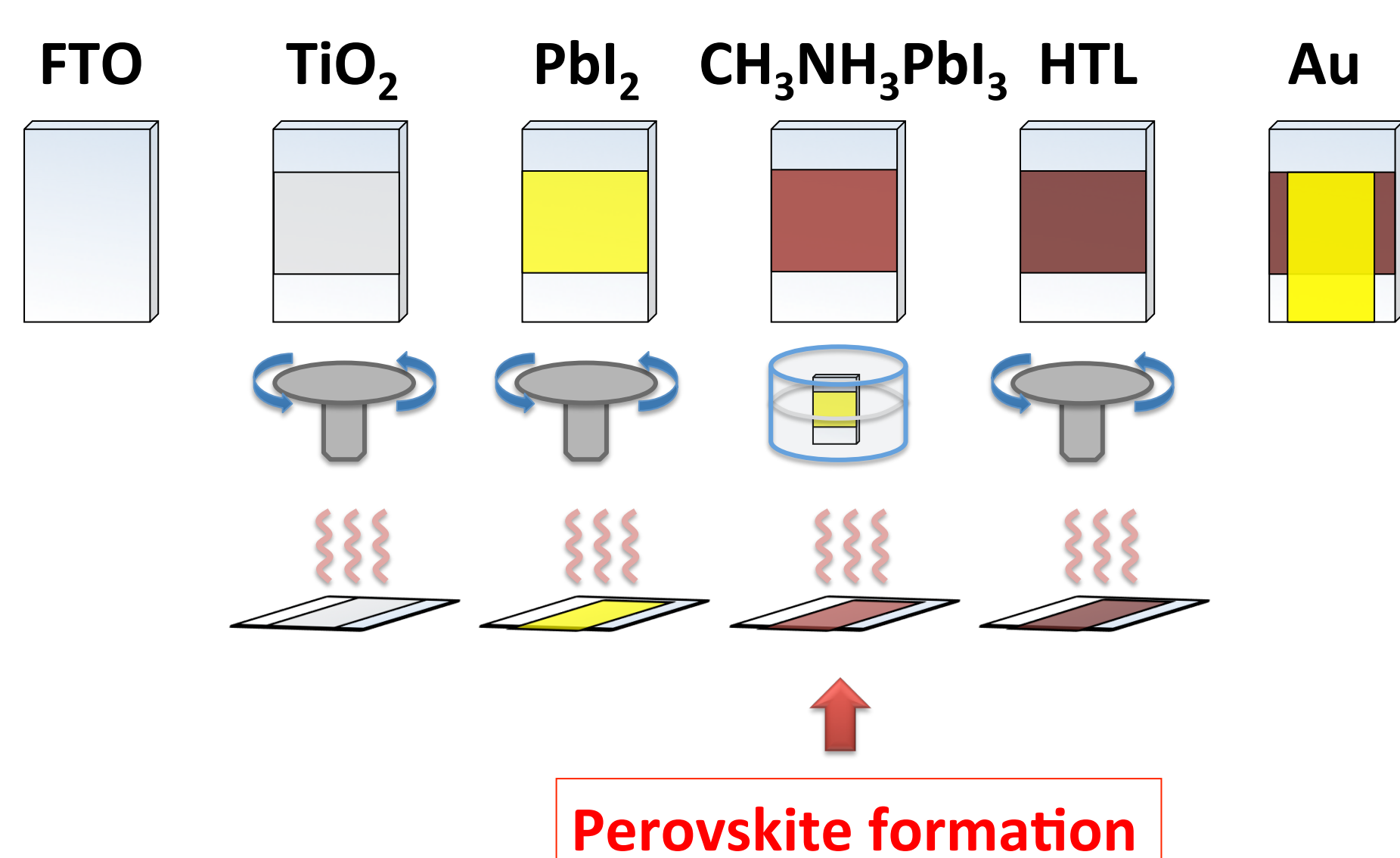


Figure 3. Perovskite solar cell fabrication process.

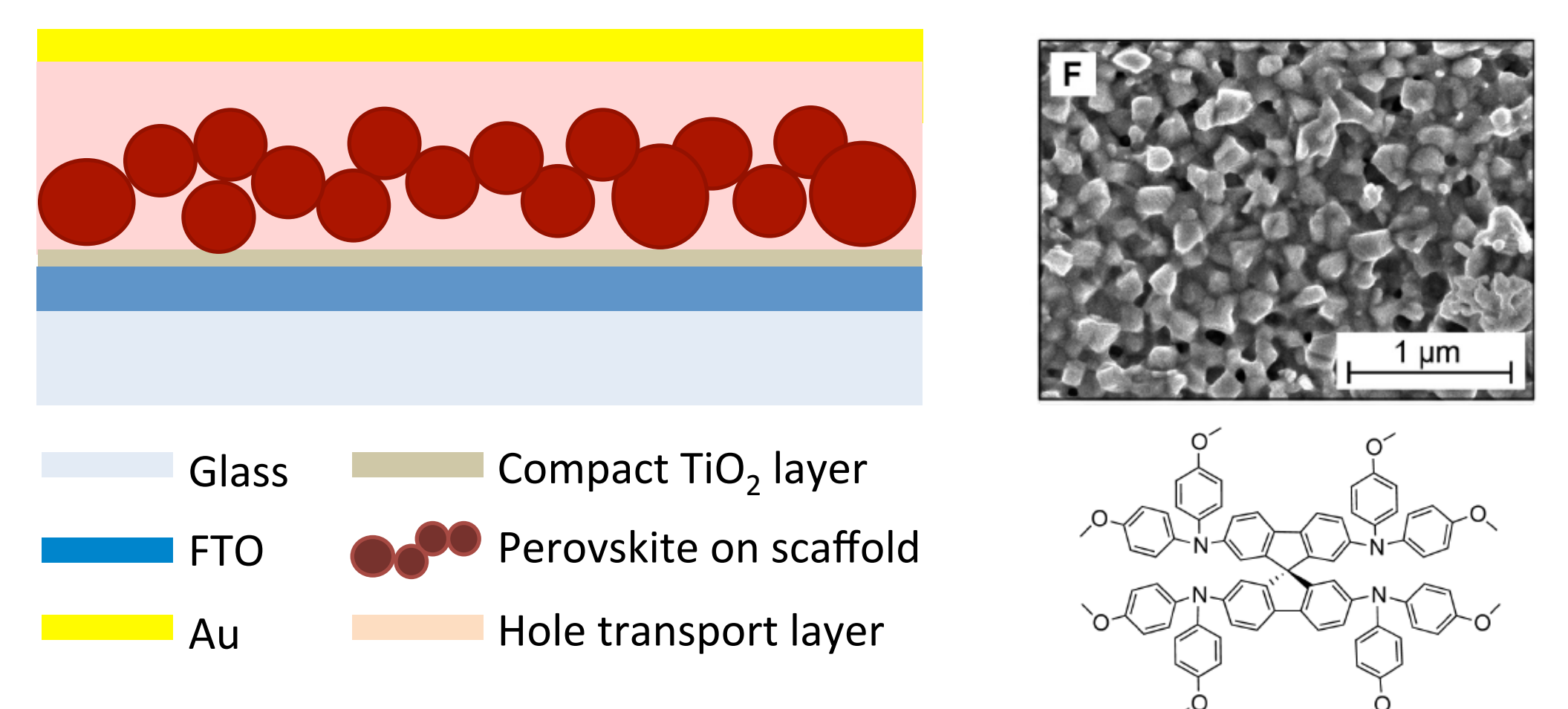


Figure 4. Device structure, SEM of perovskite on TiO₂ scaffold (Julian Burschak et al, Nature 499, 316) and molecular structure of HTL, spiro-OMETAD.

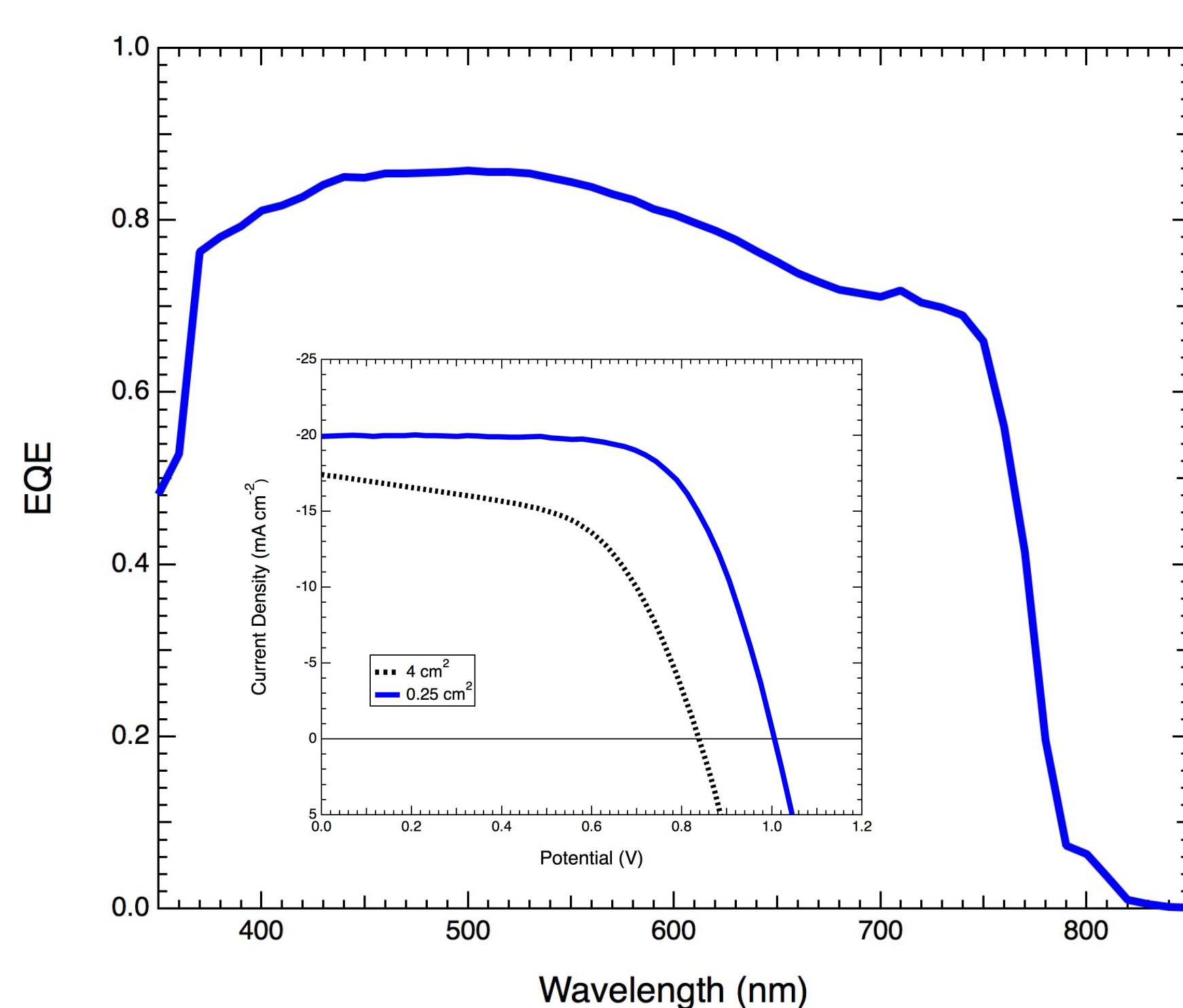
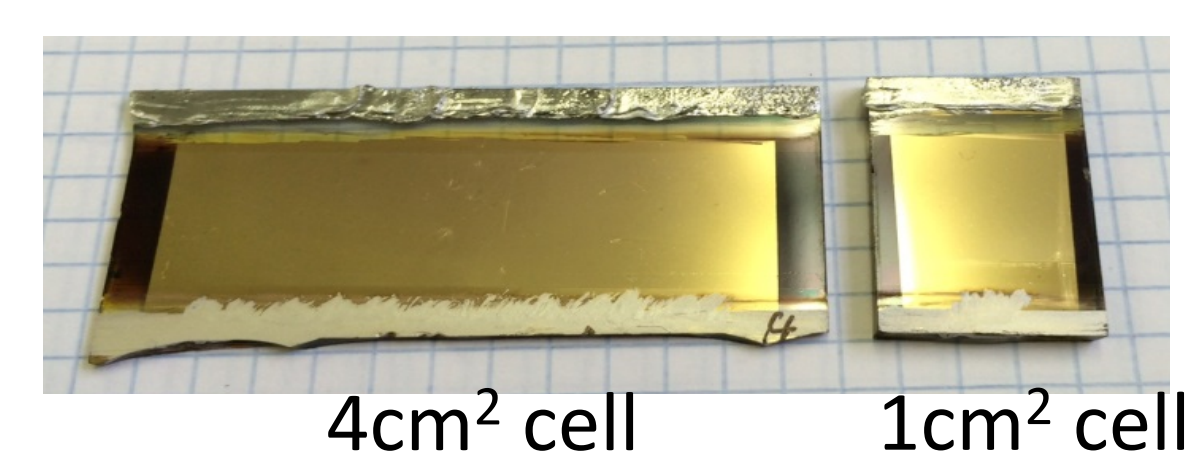


Figure 5. EQE of the best cell and (insert) IV result of perovskite solar cells with different active area.

Result



Active area	PCE [%]	Voc [mV]	Jsc [mA/cm ²]	FF [%]	Rsc [Ohms.cm ²]	Roc [Ohms.cm ²]
0.25 cm ² [a]	13.7	1010	20.0	67.7	2.63E+04	9.42
1 cm ² [a]	12.8	1030	20.4	60.8	2.10E+03	9.88
4 cm ² [b]	8.15	839	17.4	55.9	2.69E+02	12.5

[a] FTO from Pilkington, [b] FTO from CTEC

Further work

New pin-hole free compact layer development in order to mitigate recombination loss
Process engineering for large substrate to achieve uniform layers
Minimodule development with the use of laser scribing